

Strain-induced Effects In Advanced Mosfets

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1;Strain-Induced Effectsin Advanced MOSFETs;3 1.1;Preface;7 1.2;Contents;9 1.3;List of Symbols;13 1.4;Chapter 1: Introduction;15 1.5;Chapter 2: Scaling, Power Consumption, and Mobility Enhancement Techniques;18 1.5.1;2.1 Power Scaling;18 1.5.2;2.2 Strain Engineering;19 1.5.3;2.3 Global Strain Techniques and Substrate Engineering;21 1.5.4;2.4 Local Stress Techniques;23 1.5.5;2.5 Advanced Stress Techniques;25 1.5.6;2.6 Hybrid Orientation Technology and Alternative Channel Materials;27 1.5.7;References;29 1.6;Chapter 3: Strain and Stress;36 1.6.1;3.1 Strain Definition;36 1.6.2;3.2 Stress;38 1.6.3;3.3 Relation Between Strain and Stress Tensor in Silicon and Germanium;40 1.6.4;3.4 Strain and Stress Tensors: Examples;41 1.6.4.1;3.4.1 Uniform All-Around Compression;41 1.6.4.2;3.4.2 Biaxial Strain Resulting From Epitaxial Growth;42 1.6.4.3;3.4.3 Uniaxial Stress;45 1.6.5;References;47 1.7;Chapter 4: Basic Properties of the Silicon Lattice;48 1.7.1;4.1 Crystal Structure of Silicon and Germanium;48 1.7.2;4.2 Reciprocal Lattice and First Brillouin Zone;52 1.7.3;4.3 Particle in a Periodic Potential;54 1.7.4;References;57 1.8;Chapter 5: Band Structure of Relaxed Silicon;58 1.8.1;5.1 Conduction and Valence Bands;58 1.8.2;5.2 First-Principle Band Structure Calculations;59 1.8.3;5.3 Pseudopotential Band Structure Calculations;62 1.8.4;5.4 Semi-Empirical Tight Binding Method;69 1.8.5;5.5 Comparison Between Different Numerical Methods;71 1.8.6;References;74 1.9;Chapter 6: Perturbative Methods for Band Structure Calculations in Silicon;76 1.9.1;6.1 The k_p Method for a Non-Degenerate Band;76 1.9.2;6.2 Effective Mass Theory for Non-Degenerate Bands;77 1.9.2.1;6.2.1 Electron Effective Mass in Relaxed Silicon;79 1.9.2.2;6.2.2 Approximations for the Conduction Band Dispersion at Higher Energies;80 1.9.3;6.3 Valence Band;83 1.9.3.1;6.3.1 Spin Orbit Coupling in the Valence Band;85 1.9.3.2;6.3.2 Dispersion of the Valence Band in Silicon;88 1.9.3.3;6.3.3 Luttinger Parameters;89 1.9.4;References;93 1.10;Chapter 7: Strain Effects on the Silicon Crystal Structure;95 1.10.1;7.1 Strain-Induced Symmetry Reduction of Silicon Crystal Lattice;95 1.10.1.1;7.1.1 Oh Symmetry;95 1.10.1.2;7.1.2 D_{4h} Symmetry;96 1.10.1.3;7.1.3 D_{3d} Symmetry;97 1.10.1.4;7.1.4 D_{2h} Symmetry;97 1.10.1.5;7.1.5 C_{2h} Symmetry;98 1.10.2;7.2 Internal Strain Parameter;98 1.10.3;7.3 Strain and Symmetry of the Brillouin Zone;100 1.10.4;References;102 1.11;Chapter 8: Strain Effects on the

Silicon Band Structure;103 1.11.1;8.1 Linear Deformation Potential Theory;103 1.11.1.1;8.1.1 Conduction Band;103 1.11.1.2;8.1.2 Valence Band;105 1.11.1.3;8.1.3 Stress-Induced Band Splitting of the Valence Bands;106 1.11.2;8.2 Inclusion of Strain into Perturbative Band Structure Calculations;109 1.11.3;8.3 Empirical Pseudopotential Method with Strain;114 1.11.4;References;115 1.12;Chapter 9: Strain Effects on the Conduction Band of Silicon;116 1.12.1;9.1 Limitation of the Effective Mass Approximation for the Conduction Band of Silicon;116 1.12.2;9.2 The Two-Band k_p Model;118 1.12.2.1;9.2.1 Valley Shift Due to Shear Strain;119 1.12.2.2;9.2.2 Stress-Dependent Transversal Effective Masses;122 1.12.2.3;9.2.3 Dependence on Strain of the Longitudinal Effective Mass;123 1.12.2.4;9.2.4 Stress and Non-Parabolicity;126 1.12.2.5;9.2.5 Comparison of the Two-Band k_p Model with Strain to the Empirical Pseudo-Potential Calculations;129 1.12.3;References;131 1.13;Chapter 10: Electron Subbands in Silicon in the Effective Mass Approximation;133 1.13.1;10.1 Arbitrary Substrate Orientation;133 1.13.2;10.2 Substrate Orientation (001);136 1.13.3;10.3 Substrate Orientation (110);137 1.13.4;10.4 Substrate Orientation (111);138 1.13.5;References;139 1.14;Chapter 11: Electron Subbands in Thin Silicon Films;140 1.14.1;11.1 Numerical Methods for Subband Structure Calculations;140 1.14.2;11.2 Linear Combination of Bulk Bands' Method;141 1.14.3;11.3 Unprime EAN/ISBN : 9783709103821 Publisher(s): Springer, Berlin, Springer, Wien Discussed keywords: MOSFET Format: ePub/PDF Author(s): Sverdlov, Viktor

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